

GPON ONU BOSA

BA-33 series T1.25G/R2.5G

Features

- Single fiber receptacle type bi-directional transmission design for digital communication
- Asymmetric 2.5Gbps downstream and 1.25Gbps upstream data link transmission
- Laser welded transmitter and epoxy cured receiver package
- Integrated micro-optics WDM filters for dual wavelength Tx/Rx operation at 1310/1490nm
- 1310nm InGaAsP/InP MQW DFB laser diode transmission with high bandwidth InGaAs monitor photodiode
- 1490nm digital APD with integrated 2.5Gbps, 3.3V continuous mode transimpedance-amplifier
- High optical isolation from external source and low optical cross-talk from internal source
- -5°C to +75°C extended commercial temperature and -40°C to +85°C industrial operating temperature available with excellent temperature dependent power tracking error

Description

This BOSA is a high performance optical sub-assembly in single fiber by using 1310nm transmitter and 1490nm receiver.

The transmitter section uses a multiple quantum well 1310nm DFB laser supporting burst-mode operation. The receiver section uses a TO-can built in a long wavelength PIN diode and a 2.5Gbps transimpedance amplifier.

Applications

- GPON BOB ONU optical modem, class B+,C+
- GPON ONU transceiver
- FTTH Bi-directional play

Standard

- Compliant with ITU-T G984.5 telecommunication protocol
- Compliant with Telcordia GR-468 reliability test criterion
- Compliant with Telcordia GR-326 connector qualification standard
- Compliant with RoHS6 standard

1. Absolute Maximum Ratings

Item	Unit	Min	Max	Note
Forward Current for LD	mA	—	120	
Reverse Voltage for LD	V	—	2	
Forward Current for MPD	mA	—	2	
Reverse Voltage for MPD	V	—	15	
Optical Power for Rx	dBm	5	—	
APD Forward Current	mA	—	2	
APD Reverse Current	mA	—	3	
APD Reverse Voltage	V		Vbr	
TIA Supply Voltage	V	-0.4	4	
Operating Temp	°C	-5	75	
Storage Temperature	°C	-40	85	
Storage Relative Humidity	%	—	85	
Solder Reflow Temperature	°C	—	260	(*1)

(*1): For soldering by iron and 10 seconds on leads

2. Transmitter Electro-Optical Characteristics ($T_c=25^\circ\text{C}$, CW)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Threshold Current	I_{th}	$T_c=25^\circ\text{C}$	—	10	15	mA
		$T_c=0\sim70^\circ\text{C}$	1	—	50	mA
Optical Output Power (*2)	P_f	$I_f=I_{th}+20\text{mA}, T_c=25^\circ\text{C}$	1.6	—	3.5	mW
		$I_f=I_{th}+20\text{mA}, T_c=-5\sim75^\circ\text{C}$	1.0	—	—	mW
Slope Efficiency	η	$I_f=I_{th}+20\text{mA}, T_c=25^\circ\text{C}$	0.08	—	0.175	mW/mA
		$I_f=I_{th}+20\text{mA}, T_c=-5\sim75^\circ\text{C}$	0.05	—	—	mW/mA
Forward Current	I_f	$P_f=2.5\text{mW}, T_c=-5\sim75^\circ\text{C}$	—	—	70	mA
Forward Voltage	V_f	$I_f=I_{th}+20\text{mA}$	—	1.1	1.5	V
Rise/Fall Time	τ_r/τ_f	20%~80%	—	0.1	0.2	ns
Peak Wavelength	λ	$I_f=I_{th}+20\text{mA}, T_c=25^\circ\text{C}$	1300	1310	1320	nm
		$I_f=I_{th}+20\text{mA}, T_c=-5\sim75^\circ\text{C}$	1290	—	1330	nm

Spectrum Width (RMS)	$\Delta\lambda$	If=Ith+20mA, Tc=5~75°C	-	0.32	1.0	nm
Side Mode Suppression Ratio	SMSR	If=Ith+20mA, Tc=5~75°C	30	-	-	dB
Monitor Current	Im	If=Ith+20mA, Tc=5~75°C	100	-	1000	μ A
Monitor Dark Current	Id	Vrp=5V	-	-	100	nA
Monitor Capacitance	C	Vrp=5V, f=1MHz	4	-	15	pF
Tracking Error (*3)	TE	Tc =-5~75°C	-1.5	-	1.5	dB

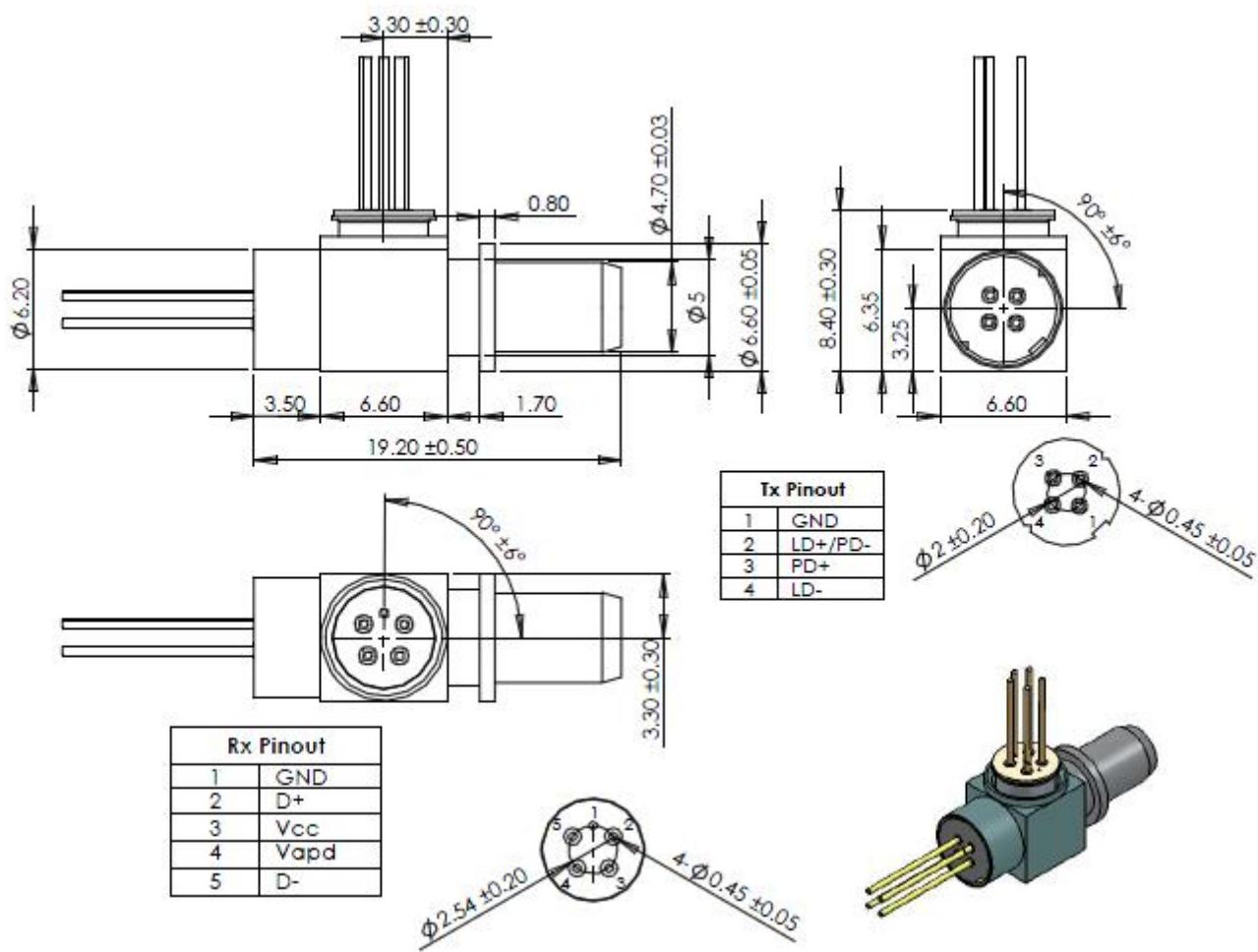
(*2): Launched into 9/125 μ m SMF, measured with a master plug and an extra receptacle

(*3): $\Delta Pf = 10 \times \log(Pf(Tc)/Pf(25^\circ C))$, Im hold(@Pf=2mW, 25°C)

3. Receiver Electro-Optical Characteristics (Tc=25°C, Vcc=3.3V)

Item	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Supply Voltage	Vcc	No loads	3.0	3.3	3.6	V
Supply Current	Icc	No loads	-	20	24	mA
Operating Wavelength	λ	Tc=-5~75°C	1480	-	1500	nm
Sensitivity	Sen	2.5Gbps, PRBS23, ER=10dB, BER=10E-10, RL=50Ω, NRZ	-	-	-29.5	dBm
Overload	OL		-7.0	-	-	dBm
Output Impedance	Rout	Single end	40	-	60	Ω
Differential Output Voltage	Vpp	100Ω differential load, 2.5Gbps	-	-	1000	mV
Dark Current	Id	Vapd=Vbr-3V	-	-	150	nA
Optical Return Loss	ORL1310	1310nm	-	-	-12	dB
	ORL1490	1490nm	-	-	-15	dB
Optical Crosstalk	X-talk	1310nm/1490nm	-	-	-47	dB
Optical Isolation from External Source	ISO1	$\lambda=1441\sim1450\text{nm}$	25	-	-	dB
		$\lambda=1530\sim1539\text{nm}$				
	ISO2	$\lambda=1260\sim1440\text{nm}$	35	-	-	dB
		$\lambda=1540\sim1625\text{nm}$				

4. Dimension Outline



5. Other Characteristics ($T_c=25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Note
Fiber Mode Field Diameter		8	9	10	μm	
Pull Force on LD Assembly		30	--	--	Kgw	
Pull Force on APD Assembly		15	--	--	Kgw	
Shear Strength on XY Welding		30	--	--	Kgw	
Connector Repeatability (*4)		-1.0	-	+1.0	dB	

(*4): Same plug orientation, same patchcord, 5 times, Launched into 9/125 μm SMF, measured with a master plug and an extra receptacle